

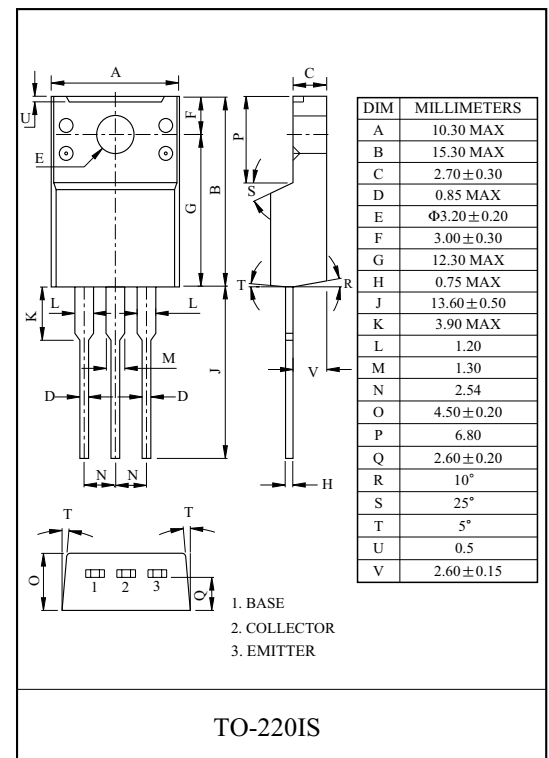
MONOLITHIC CONSTRUCTION WITH BUILT IN  
BASE-EMITTER SHUNT RESISTORS INDUSTRIAL USE.

### FEATURES

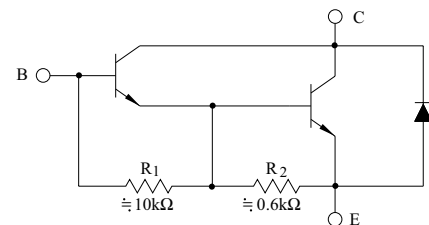
- High DC Current Gain.  
:  $h_{FE}=1000(\text{Min.})$ , @  $V_{CE}=4V$ ,  $I_C=1A$ .
- Low Collector-Emitter Saturation Voltage.
- Complementary to TIP117F.

### MAXIMUM RATING (Ta=25°C)

| CHARACTERISTIC              | SYMBOL    | RATING    | UNIT  |
|-----------------------------|-----------|-----------|-------|
| Collector-Base Voltage      | $V_{CBO}$ | 100       | V     |
| Collector-Emitter Voltage   | $V_{CEO}$ | 100       | V     |
| Emitter-Base Voltage        | $V_{EBO}$ | 5         | V     |
| Collector Current           | DC        | $I_C$     | A     |
|                             | Pulse     | $I_{CP}$  |       |
| Base Current                | DC        | $I_B$     | 50 mA |
| Collector Power Dissipation | Ta=25°C   | $P_C$     | 2     |
|                             | Tc=25°C   |           | 20    |
| Junction Temperature        | $T_j$     | 150       | °C    |
| Storage Temperature Range   | $T_{stg}$ | -65 ~ 150 | °C    |



### EQUIVALENT CIRCUIT



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

| CHARACTERISTIC                       | SYMBOL         | TEST CONDITION                      | MIN. | TYP. | MAX. | UNIT |
|--------------------------------------|----------------|-------------------------------------|------|------|------|------|
| Collector Cut-off Current            | $I_{CEO}$      | $V_{CE}=50V$ , $I_B=0$              | -    | -    | 2    | mA   |
|                                      | $I_{CBO}$      | $V_{CB}=100V$ , $I_E=0$             | -    | -    | 1    |      |
| Emitter Cut-off Current              | $I_{EBO}$      | $V_{EB}=5V$ , $I_C=0$               | -    | -    | 2    | mA   |
| DC Current Gain                      | $h_{FE}$       | $V_{CE}=4V$ , $I_C=1A$              | 1000 | -    | -    |      |
|                                      |                | $V_{CE}=4V$ , $I_C=2A$              | 500  | -    | -    |      |
| Collector-Emitter Sustaining Voltage | $V_{CEO(SUS)}$ | $I_C=30mA$ , $I_B=0$                | 100  | -    | -    | V    |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$  | $I_C=2A$ , $I_B=8mA$                | -    | -    | 2.5  | V    |
| Base-Emitter On Voltage              | $V_{BE(ON)}$   | $V_{CE}=4V$ , $I_C=2A$              | -    | -    | 2.8  | V    |
| Collector Output Capacitance         | $C_{ob}$       | $V_{CB}=10V$ , $I_E=0$ , $f=0.1MHz$ | -    | -    | 100  | pF   |

# TIP112F

